TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS176D

November 1997 - Revised October 2003

Features

- Adds Two Binary Numbers
- Full Internal Lookahead
- Fast Ripple Carry for Economical Expansion
- · Operates with Both Positive and Negative Logic
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, IJ \leq 1 μA at V_OL, V_OH

CD54HC283, CD74HC283, CD54HCT283, CD74HCT283

High-Speed CMOS Logic 4-Bit Binary Full Adder with Fast Carry

Description

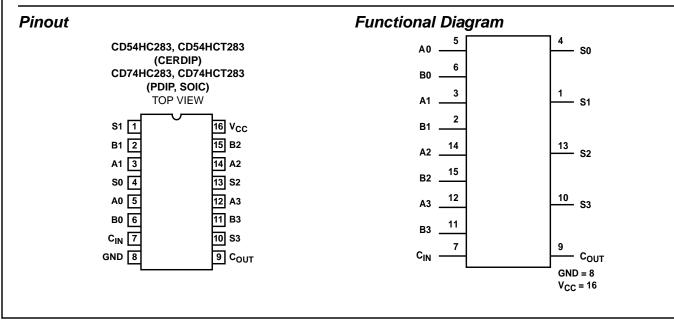
The 'HC283 and 'HCT283 binary full adders add two 4-bit binary numbers and generate a carry-out bit if the sum exceeds 15.

Because of the symmetry of the add function, this device can be used with either all active-high operands (positive logic) or with all active-low operands (negative logic). When using positive logic the carry-in input must be tied low if there is no carry-in.

Ordering Information

| PART NUMBER | TEMP. RANGE (°C) | PACKAGE |
|---------------|------------------|--------------|
| CD54HC283F3A | -55 to 125 | 16 Ld CERDIP |
| CD54HCT283F3A | -55 to 125 | 16 Ld CERDIP |
| CD74HC283E | -55 to 125 | 16 Ld PDIP |
| CD74HC283M | -55 to 125 | 16 Ld SOIC |
| CD74HC283MT | -55 to 125 | 16 Ld SOIC |
| CD74HC283M96 | -55 to 125 | 16 Ld SOIC |
| CD74HCT283E | -55 to 125 | 16 Ld PDIP |
| CD74HCT283M | -55 to 125 | 16 Ld SOIC |
| CD74HCT283MT | -55 to 125 | 16 Ld SOIC |
| CD74HCT283M96 | -55 to 125 | 16 Ld SOIC |

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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Absolute Maximum Ratings

| DC Supply Voltage, V _{CC} 0.5 DC Input Diode Current, I _{IK} | 5V to 7V |
|---|----------|
| For $V_l < -0.5V$ or $V_l > V_{CC} + 0.5V$ | .±20mA |
| DC Output Diode Current, I _{OK} | |
| For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$ | .±20mA |
| DC Drain Current, per Output, IO | |
| For -0.5V < V _O < V _{CC} + 0.5V | .±25mA |
| DC Output Source or Sink Current per Output Pin, IO | |
| For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$ | .±25mA |
| DC V _{CC} or Ground Current, I _{CC} | .±50mA |
| | |

Operating Conditions

| Temperature Range, T _A |
|---|
| Supply Voltage Range, V _{CC} |
| HC Types |
| DC Input or Output Voltage, V _I , V _O 0V to V _{CC} |
| Input Rise and Fall Time |
| 2V |
| 4.5V 500ns (Max) |
| 6V |
| |

Thermal Information

| Thermal Resistance (Typical, Note 1) | θ _{JA} (^o C/W) |
|--|---|
| E (PDIP) Package | |
| M (SOIC) Package | 73 |
| Maximum Junction Temperature | 150 ⁰ C |
| Maximum Storage Temperature Range | S5 ^o C to 150 ^o C |
| Maximum Lead Temperature (Soldering 10s) | |
| (SOIC - Lead Tips Only) | |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

| | | TES CONDI [®] | | Vcc | | 25°C | | -40 ^о С Т | O 85°C | -55°C TO 125°C | | |
|-----------------------------|-----------------|------------------------------------|---------------------|-----|------|------|------|----------------------|--------|----------------|------|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HC TYPES | | - | | | - | - | - | - | - | - | | |
| High Level Input | V _{IH} | - | - | 2 | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| Voltage | | | | 4.5 | 3.15 | - | - | 3.15 | - | 3.15 | - | V |
| | | | | 6 | 4.2 | - | - | 4.2 | - | 4.2 | - | V |
| Low Level Input | VIL | - | - | 2 | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| Voltage | | | | 4.5 | - | - | 1.35 | - | 1.35 | - | 1.35 | V |
| | | | | 6 | - | - | 1.8 | - | 1.8 | - | 1.8 | V |
| High Level Output | V _{OH} | V _{IH} or V _{IL} | -0.02 | 2 | 1.9 | - | - | 1.9 | - | 1.9 | - | V |
| /oltage CMOS Loads | | | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| | | | -0.02 | 6 | 5.9 | - | - | 5.9 | - | 5.9 | - | V |
| High Level Output | | | - | - | - | - | - | - | - | - | - | V |
| Voltage TTL Loads | | | -4 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| | | | -5.2 | 6 | 5.48 | - | - | 5.34 | - | 5.2 | - | V |
| Low Level Output | V _{OL} | V _{IH} or V _{IL} | 0.02 | 2 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Voltage CMOS Loads | | | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| CINCO LUAUS | | | 0.02 | 6 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output | | | - | - | - | - | - | - | - | - | - | V |
| Voltage TTL Loads | | | 4 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| | | | 5.2 | 6 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | lı | V _{CC} or GND | - | 6 | - | - | ±0.1 | - | ±1 | - | ±1 | μA |
| Quiescent Device Current | ICC | V _{CC} or GND | 0 | 6 | - | - | 8 | - | 80 | - | 160 | μA |

CD54HC283, CD74HC283, CD54HCT283, CD74HCT283

DC Electrical Specifications (Continued)

| | | TES CONDI | | V _{CC} | | 25 ⁰ C | | -40°C T | O 85°C | -55°C T | O 125ºC | |
|--|------------------------------|------------------------------------|---------------------|-----------------|------|-------------------|------|---------|--------|---------|---------|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HCT Types | | | | | | | | | | | | |
| High Level Input Voltage | VIH | - | - | 4.5 to 5.5 | 2 | - | - | 2 | - | 2 | - | V |
| Low Level Input Voltage | VIL | - | - | 4.5 to 5.5 | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| High Level Output Voltage CMOS Loads | V _{OH} | V _{IL} or V _{IH} | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| High Level Output Voltage TTL Loads | V _{OH} | V _{IL} or V _{IH} | -4 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| Low Level Output Voltage CMOS Loads | V _{OL} | V _{IH} or V _{IL} | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output Voltage TTL Loads | V _{OL} | V _{IH} or V _{IL} | 4 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | lı | V _{CC} to GND | - | 5.5 | - | - | ±0.1 | - | ±1 | - | ±1 | μA |
| Quiescent Device Current | ICC | V _{CC} or GND | - | 5.5 | - | - | 8 | - | 80 | - | 160 | μA |
| Additional Quiescent Device Current Per Input Pin: 1 Unit Load | ΔI _{CC} (Note 2) | V _{CC} - 2.1 | - | 4.5 to 5.5 | - | 100 | 360 | - | 450 | - | 490 | μA |

NOTE:

2. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

| INPUT | UNIT LOADS |
|-----------------|------------|
| C _{IN} | 1.5 |
| B1, A1, A0 | 1 |
| B0 | 0.4 |
| B3, A3, A2, B2 | 0.5 |

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

Switching Specifications Input t_r, t_f = 6ns

| | | TEST | | | 25 ⁰ C | | -40 ⁰ 85 | с то °С | -55 ⁰ 125 | С ТО 5°С | |
|-----------------------|-------------------------------------|-----------------------|-------------|-----|-------------------|-----|------------------------|------------|-------------------------|-------------|-------|
| PARAMETER | SYMBOL | CONDITIONS | $V_{CC}(V)$ | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HC TYPES | | | | | | | | | | | |
| Propagation Delay | t _{PLH} , t _{PHL} | $C_L = 50 pF$ | 2 | - | - | 160 | - | 200 | - | 240 | ns |
| C _{IN} to S0 | | | 4.5 | - | - | 32 | - | 40 | - | 48 | ns |
| | | C _L = 15pF | 5 | - | 13 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 27 | - | 34 | - | 41 | ns |

CD54HC283, CD74HC283, CD54HCT283, CD74HCT283

| | | TEST | | | 25 ⁰ C | | | с то ⁰С | | C TO 5⁰C | |
|--|--------------------------------------|-----------------------|---------------------|-----|-------------------|-----|-----|------------|-----|-------------|----|
| PARAMETER | SYMBOL | CONDITIONS | V _{CC} (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | |
| C _{IN} to S1 | t _{PLH} , t _{PHL} | C _L = 50pF | 2 | - | - | 180 | - | 225 | - | 270 | ns |
| | | | 4.5 | - | - | 36 | - | 45 | - | 54 | ns |
| | | C _L = 15pF | 5 | - | 15 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 31 | - | 38 | - | 46 | ns |
| C_{IN} to S2, C_{IN} to C_{OUT} | t _{PLH} , t _{PHL} | C _L = 50pF | 2 | - | - | 195 | - | 245 | - | 295 | ns |
| | | | 4.5 | - | - | 39 | - | 49 | - | 59 | ns |
| | | C _L = 15pF | 5 | - | 16 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 33 | - | 42 | - | 50 | ns |
| C _{IN} to S3 | t _{PLH} , t _{PHL} | C _L = 50pF | 2 | - | - | 230 | - | 290 | - | 345 | ns |
| | | | 4.5 | - | - | 46 | - | 58 | - | 69 | ns |
| | | C _L = 15pF | 5 | - | 19 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 39 | - | 49 | - | 59 | ns |
| An, Bn to C _{OUT} | t _{PLH} , t _{PHL} | C _L = 50pF | 2 | - | - | 195 | - | 245 | - | 295 | ns |
| | , | | 4.5 | - | - | 39 | - | 49 | - | 59 | ns |
| | | C _L = 15pF | 5 | - | 16 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 33 | - | 42 | - | 50 | ns |
| An, Bn to Sn | ^t PLH, ^t PHL | C _L = 50pF | 2 | - | - | 210 | - | 265 | - | 315 | ns |
| | , | | 4.5 | - | - | 42 | - | 53 | - | 63 | ns |
| | | C _L = 15pF | 5 | - | 18 | - | - | - | - | - | ns |
| | | C _L = 50pF | 6 | - | - | 36 | - | 45 | - | 54 | ns |
| Output Transition Time | t _{TLH} , t _{THL} | C _L = 50pF | 2 | - | - | 75 | - | 95 | - | 110 | ns |
| | | | 4.5 | - | - | 15 | - | 19 | - | 22 | ns |
| | | | 6 | - | - | 13 | - | 16 | - | 19 | ns |
| Input Capacitance | C _{IN} | C _L = 50pF | - | - | - | 10 | - | 10 | - | 10 | pF |
| Power Dissipation Capacitance, (Notes 3, 4) | C _{PD} | - | 5 | - | 70 | - | - | - | - | - | pF |
| HCT TYPES | | | | | | | | | | | 1 |
| Propagation Delay | | | | | | | | | | | |
| C _{IN} to S0 | t _{PLH} , t _{PHL} | C _L = 15pF | 5 | - | 13 | - | - | - | - | - | ns |
| | | $C_L = 50 pF$ | 4.5 | - | - | 31 | - | 39 | - | 47 | ns |
| C _{IN} to S1 | t _{PLH} , t _{PHL} | C _L = 15pF | 5 | - | 18 | - | - | - | - | - | ns |
| | | $C_L = 50 pF$ | 4.5 | - | | 43 | - | 54 | - | 65 | ns |
| C_{IN} to S2, C_{IN} to C_{OUT} | t _{PLH} , t _{PHL} | C _L = 15pF | 5 | - | 19 | - | - | - | - | - | ns |
| | | $C_L = 50 pF$ | 4.5 | - | | 46 | - | 58 | - | 69 | ns |
| C _{IN} to S3 | t _{PLH} , t _{PHL} | C _L = 15pF | 5 | - | 22 | - | - | - | - | - | ns |
| | | $C_L = 50 pF$ | 4.5 | - | | 53 | - | 66 | - | 80 | ns |
| An, Bn to C _{OUT} | t _{PLH} , t _{PH} L | C _L = 15pF | 5 | - | 20 | - | - | - | - | - | ns |
| | | C _L = 50pF | 4.5 | - | | 48 | - | 60 | - | 72 | ns |
| An, Bn to Sn | t _{PLH} , t _{PHL} | C _L = 15pF | 5 | - | 21 | - | - | - | - | - | ns |
| | | C _L = 50pF | 4.5 | - | | 49 | - | 61 | - | 74 | ns |
| Output Transition Time | t _{TLH} , t _{THL} | C _L = 50pF | 4.5 | - | | 15 | - | 19 | - | 22 | ns |

| | | TEST | | | 25 ⁰ C | | -40 ^о С ТО 85 ^о С | | -55 ^o C TO 125 ^o C | | |
|--|-----------------|------------|---------------------|-----|-------------------|-----|--|-----|---|-----|-------|
| PARAMETER | SYMBOL | CONDITIONS | V _{CC} (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| Input Capacitance | C _{IN} | - | - | - | - | 10 | - | 10 | - | 10 | pF |
| Power Dissipation Capacitance, (Notes 3, 4) | C _{PD} | - | 5 | - | 82 | - | - | - | - | - | pF |

NOTES:

3. C_{PD} is used to determine the dynamic power consumption, per package.

4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where: $f_i =$ Input Frequency, $C_L =$ Output Load Capacitance, $V_{CC} =$ Supply Voltage.

Test Circuits and Waveforms

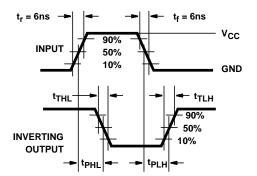


FIGURE 1. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

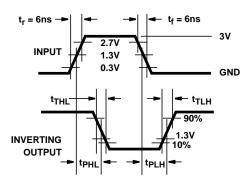


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



10-Jun-2014

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|--------------------------------|
| 5962-8976501EA | ACTIVE | CDIP | J | 16 | 1 | TBD | A42 | N / A for Pkg Type | -55 to 125 | 5962-8976501EA CD54HC283F3A |
| CD54HC283F3A | ACTIVE | CDIP | J | 16 | 1 | TBD | A42 | N / A for Pkg Type | -55 to 125 | 5962-8976501EA CD54HC283F3A |
| CD54HCT283F3A | ACTIVE | CDIP | J | 16 | 1 | TBD | A42 | N / A for Pkg Type | -55 to 125 | CD54HCT283F3A |
| CD74HC283E | ACTIVE | PDIP | N | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -55 to 125 | CD74HC283E |
| CD74HC283EE4 | ACTIVE | PDIP | Ν | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -55 to 125 | CD74HC283E |
| CD74HC283M | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HC283M |
| CD74HC283M96 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HC283M |
| CD74HC283M96E4 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HC283M |
| CD74HC283ME4 | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HC283M |
| CD74HC283MG4 | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HC283M |
| CD74HC283MT | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HC283M |
| CD74HCT283E | ACTIVE | PDIP | Ν | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -55 to 125 | CD74HCT283E |
| CD74HCT283EE4 | ACTIVE | PDIP | N | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -55 to 125 | CD74HCT283E |
| CD74HCT283M | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT283M |
| CD74HCT283M96 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT283M |
| D74HCT283M96G4 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT283M |
| CD74HCT283MG4 | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT283M |



10-Jun-2014

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|--------------------|--------------|-------------------------|
| CD74HCT283MT | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT283M |
| CD74HCT283MTE4 | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -55 to 125 | HCT283M |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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10-Jun-2014

OTHER QUALIFIED VERSIONS OF CD54HC283, CD54HCT283, CD74HC283, CD74HCT283 :

- Catalog: CD74HC283, CD74HCT283
- Military: CD54HC283, CD54HCT283

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

TEXAS INSTRUMENTS www.ti.com

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|------|--------------------|----|------|--------------------------|--------------------------|---------|---------|---------|------------|-----------|------------------|
| Device | | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| CD74HC283M96 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| CD74HCT283M96 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CD74HC283M96 | SOIC | D | 16 | 2500 | 333.2 | 345.9 | 28.6 |
| CD74HCT283M96 | SOIC | D | 16 | 2500 | 333.2 | 345.9 | 28.6 |

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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